Reliability Results for Product Type PMEG2015EJ

Time period: Q1/2018 to Q4/2018

Test Results

AEC-Q101 Test		Conditions	Duration	Quantity	Rejects
# 1	**TEST** Pre- and Post-Stress Electrical Test	T_{amb} = 25 °C	N/A	all parts	see below
# 2	**PC** Preconditioning	JESD22-A113 Bake T_{amb} = 125 °C Soak T_{amb} = 85 °C, RH = 85% Reflow soldering	24 hours 168 hours 3 cycles	37120	0
# 5	**HTRB** High Temperature Reverse Bias	MIL-STD-750-1 M1038 Method A $T_j = T_{jmax}$, Vr = 100% of max. datasheet reverse voltage[1]	1000 hours	4400	0
# 7	**TC** Temperature Cycling	JESD22-A104 -55 °C to T_{jmax}, not to exceed 150°C	1000 cycles	9280	0
# 8	**AC** Autoclave	JESD22-A102 T_{amb} = 121 °C, RH = 100 % Pressure = 205 kPa (29.7 psia)	96 hours	9280	0
# 9	**H3TRB** High Humidity High Temperature Reverse Bias	JESD22-A101 T_{amb} = 85 °C, RH = 85%, V_R > 80 % of rated reverse voltage[1]	1000 hours	9280	0
# 10	**IOL** Intermittent Operating Life	MIL-STD-750 Method 1037 $t_{on} = t_{off}$, devices powered to insure ΔT_j = 100 °C for 15000 cycles	1000 hours	9280	0
# 20	**RSH** Resistance to Solder Heat	JESD22-A111 260 °C ± 5 °C	10 s	2340	0
# 21	**SD** Solderability	J-STD-002 Test method B and D		2280	0

[1] The physical limitations of Schottky diodes have to be considered (thermal runaway).

Calculation of FIT and MTBF

Test considered for FIT calculation: High Temperature Reverse Bias (HTRB, AEC-Q101 Test # 5)
Confidence level 60%, derated to 55 °C, activation energy 0.7 eV, test time 168 to 1000 hours

Wafer Fab	Technology	Quantity	Rejects	Failure Rate	MTBF
Nexperia DHAM	Schottky	4400	0	0.97 FIT	118197 years